

SILICON POWER TRANSISTOR 2SD2165

NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

The 2SD2165 is a single power transistor developed especially for high h_{FE} . This transistor is ideal for simplifying drive circuits and reducing power dissipation because its h_{FE} is as high as that of Darlington transistors, but it is a single transistor.

In addition, this transistor features a small resin-molded insulation package, thus contributing to high-density mounting and mounting cost reduction.

FEATURES

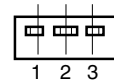
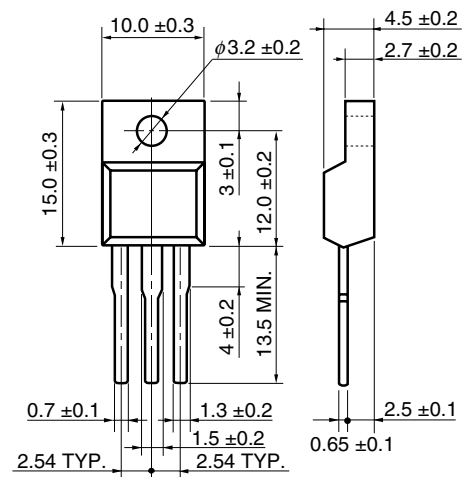
- High h_{FE} and low $V_{CE(sat)}$:
 $h_{FE} \cong 1,300$ TYP. ($V_{CE} = 5.0$ V, $I_C = 1.0$ A)
 $V_{CE(sat)} \cong 0.3$ V TYP. ($I_C = 3.0$ A, $I_B = 30$ mA)
- Mold package that does not require an insulating board or insulation bushing

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| Parameter | Symbol | Ratings | Unit |
|--|----------------|--------------------|------------------|
| Collector to base voltage | V_{CBO} | 100 | V |
| Collector to emitter voltage | V_{CEO} | 100 | V |
| Emitter to base voltage | V_{EBO} | 7.0 | V |
| Collector current (DC) | $I_{C(DC)}$ | 6.0 | A |
| Collector current (pulse) | $I_{C(pulse)}$ | 10 ^{Note} | A |
| Base current (DC) | $I_{B(DC)}$ | 1.0 | A |
| Total power dissipation ($T_C = 25^\circ\text{C}$) | P_T | 30 | W |
| Total power dissipation ($T_A = 25^\circ\text{C}$) | P_T | 2.0 | W |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

Note $PW \leq 300 \mu\text{s}$, duty cycle $\leq 10\%$

PACKAGE DRAWING (UNIT: mm)



Electrode Connection
 1. Base
 2. Collector
 3. Emitter

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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

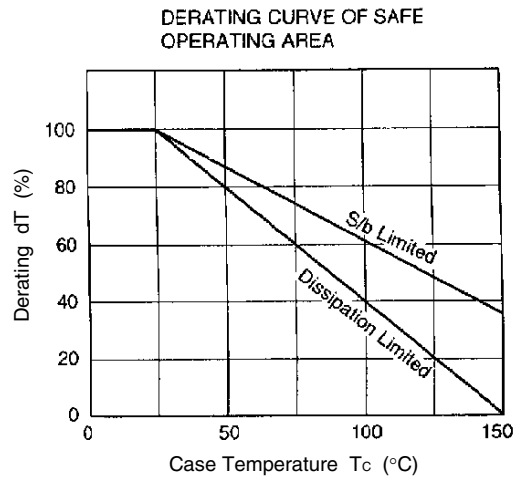
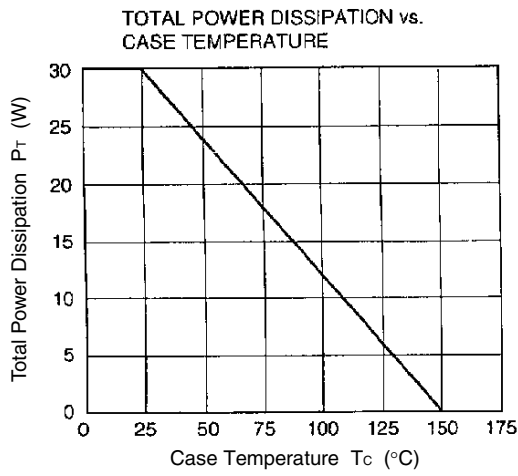
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------------|----------------------|---|------|-------|-------|------|
| Collector cutoff current | I _{CB0} | V _{CB} = 60 V, I _E = 0 A | | | 10 | μA |
| Emitter cutoff current | I _{EB0} | V _{EB} = 7.0 V, I _C = 0 A | | | 10 | μA |
| DC current gain | h _{FE1} | V _{CE} = 5.0 V, I _C = 1.0 A ^{Note} | 800 | 1,300 | 3,200 | |
| DC current gain | h _{FE2} | V _{CE} = 5.0 V, I _C = 3.0 A ^{Note} | 500 | 1,000 | | |
| ★ Collector saturation voltage | V _{CE(sat)} | I _C = 3.0 A, I _B = 30 mA ^{Note} | | 0.3 | 1.0 | V |
| Base saturation voltage | V _{BE(sat)} | I _C = 3.0 A, I _B = 30 mA ^{Note} | | | 1.2 | V |
| Gain bandwidth product | f _T | V _{CE} = 5.0 V, I _C = 0.1 A | | 110 | | MHz |
| Collector capacitance | C _{ob} | V _{CB} = 10 V, I _E = 0 A, f = 1.0 MHz | | 50 | | pF |

Note Pulse test PW ≤ 350 μs, duty cycle ≤ 2%

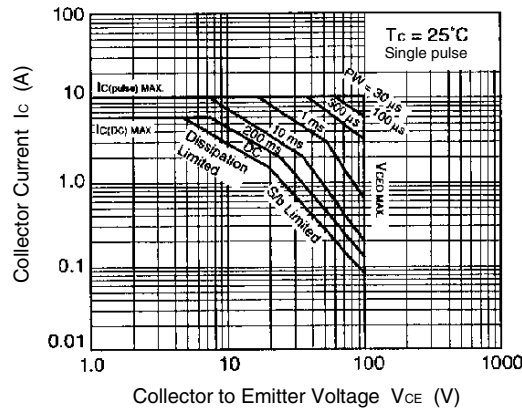
h_{FE1} CLASSIFICATION

| Marking | M | L | K |
|------------------|--------------|----------------|----------------|
| h _{FE1} | 800 to 1,600 | 1,000 to 2,000 | 1,600 to 3,200 |

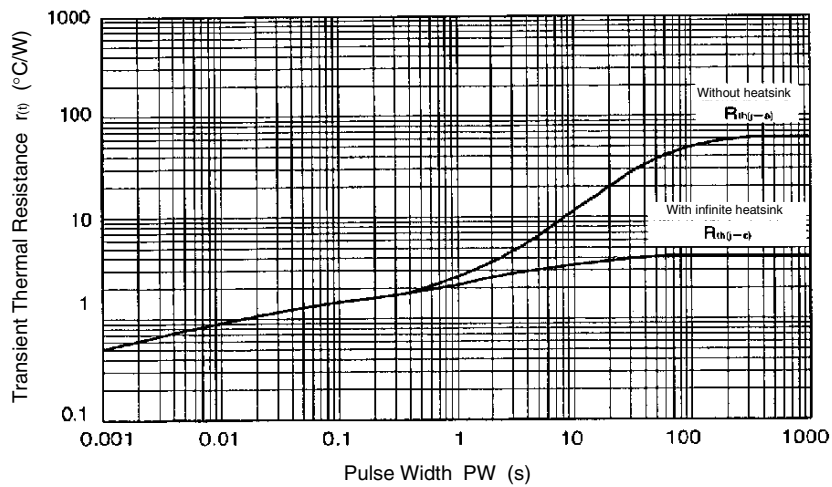
TYPICAL CHARACTERISTICS (T_A = 25°C)



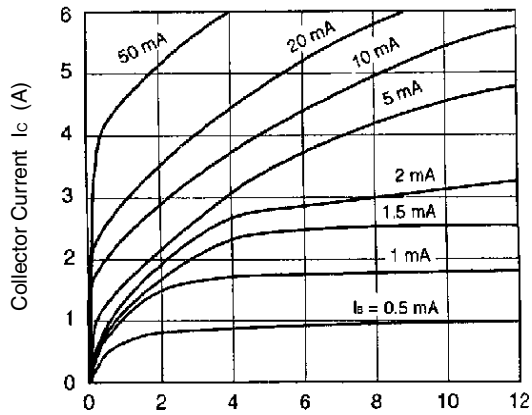
FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

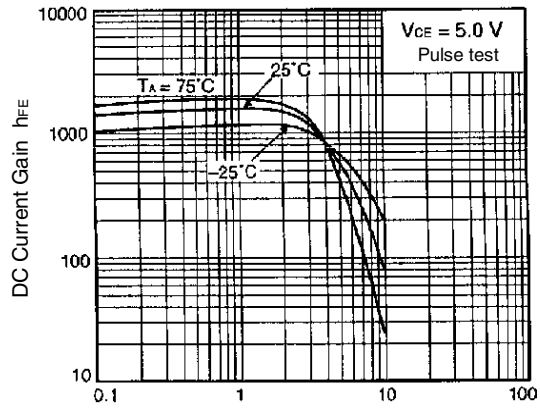


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



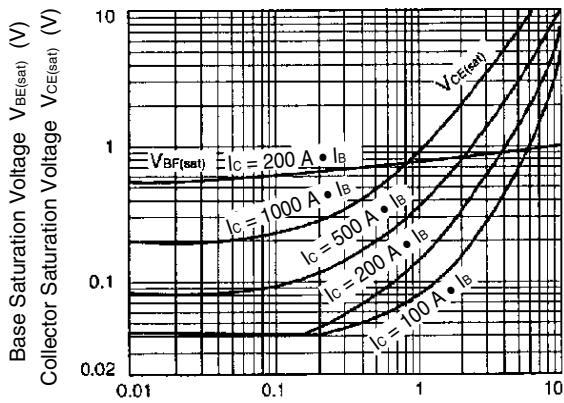
Collector to Emitter Voltage V_{CE} (V)

DC CURRENT GAIN vs. COLLECTOR CURRENT



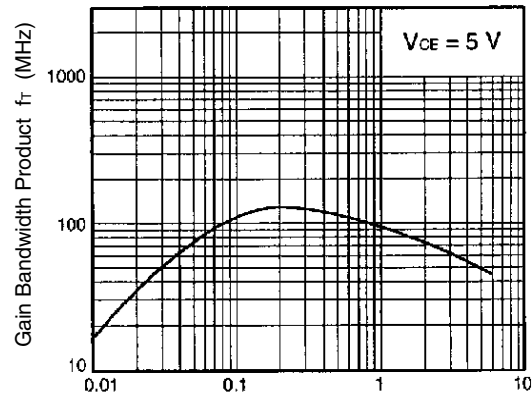
Collector Current I_c (A)

COLLECTOR AND BASE SATURATION VOLTAGE vs. COLLECTOR CURRENT



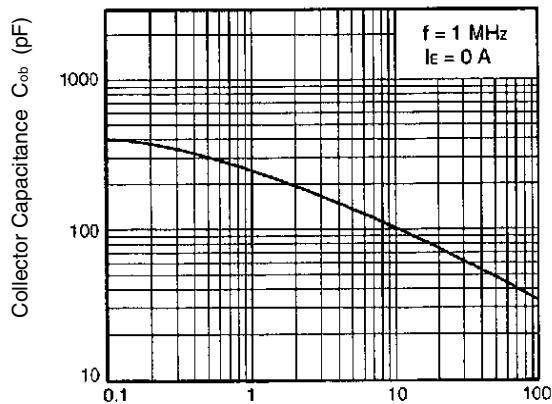
Collector Current I_c (A)

GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



Collector Current I_c (A)

OUTPUT CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



Collector to Base Voltage V_{CB} (V)

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